NSN 5961-01-274-9252

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View Online at https://aerobasegroup.com/nsn/5961-01-274-9252 **Inclosure Material:** Metal **Overall Length:** 1.253 inches **Function For Which Designed:** Zener diode **Mounting Facility Quantity:** Joint Electronic Device Engineering Council/jedec/case Outline Designation: **Electrode Internally-electrically Connected To Case:** Collector **Mounting Method:** Threaded stud **Features Provided:** Hermetically sealed case **Overall Width Across Flats:** 0.437 inches **Thread Size:** 0.190 inches **Criticality Code Justification:** Feat **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 16.0 regulator voltage **Voltage Tolerance In Percent:** -2.0/+2.0**Current Rating Per Characteristic:** 530.00 milliamperes repetitive peak forward current **Power Rating Per Characteristic:** 10.0 watts small-signal input power, common-collector absolute **Maximum Operating Tempurature Per Measurement Point:** 175.0 degrees celsius junction **Special Features:** Item must comply with requirements of defense electronics supply center production standard no. L03965; for navy nuclear propulsion plant products only; junction pattern arrangement: pn **Thread Series Designator:** Unf

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Terminal Type And Quantity:

1 tab, solder lug and 1 threaded stud

Shelf Life:

N/a

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Demilitarization:

No

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